

Why pressure induces an abrupt structural rearrangement in PdTe₂ but not in PtTe₂

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Abstract

High-pressure X-ray diffraction measurements were carried out for polymeric CdI₂-type compounds *M*Te₂ (*M* = Pt, Pd) to investigate if they undergo a structural phase transition under pressure as does IrTe₂. Up to 27 GPa at room temperature PtTe₂ does not undergo any structural phase transition. In contrast, however, an abrupt change in the inter-atomic distances occurs in PdTe₂ above 15.7 GPa at room temperature, and above 5 GPa at 300 °C, but the volume vs. pressure curve exhibits no discontinuity. To account for the differences between the isostructural compounds PtTe₂, PdTe₂ and IrTe₂, their electronic structures and bonding were analyzed on the basis of first principles electronic band structure calculations.

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1. Introduction

The CdI₂-type transition metal dichalcogenides *MQ*₂ (*M* = transition metal, *Q* = chalcogen) consist of *MQ*₂ layers made up of edge-sharing *MQ*₆ octahedra, where adjacent *MQ*₂ layers are held together by van der Waals interactions. IrTe₂ adopts the polymeric CdI₂-type structure, i.e., a derivative of the CdI₂-type structure [1,2], in which adjacent *MQ*₂ layers have short *Q*...*Q* contacts thereby leading to a low *c/a* ratio, i.e., 1.38 instead of 1.67 expected on the basis of a classical hexagonal close stacking of the anions. From the viewpoint of the ionic electron counting leading to the charge balance *M*⁴⁺(*Q*²⁻)₂, the occurrence of short

interlayer *Q*...*Q* contacts is explained by considering the electron transfer from the *p*-block bands of *Q* to the *d*-block bands of *M* [3]. When the polymeric CdI₂-type IrTe₂ [2] (hereafter named h-IrTe₂) is subjected to pressure up to 32 GPa, it undergoes two structural phase transitions [4-6]. The hexagonal phase h-IrTe₂ is converted to a monoclinic-type structure (m-IrTe₂) at 5 GPa and at room temperature, and then to a pyrite structure (c-IrTe₂) at 32 GPa under laser heating.

PtTe₂ and PdTe₂ are similar to IrTe₂ in several structural and electronic properties under ambient conditions. They both adopt the polymeric CdI₂-type structure [7,8] with a low *c/a* ratio (i.e., 1.30 in PtTe₂ and 1.27 in PdTe₂). The three compounds IrTe₂, PtTe₂ and PdTe₂ have similar cell volumes per formula unit (i.e., 72.23(1) Å³ for IrTe₂, 72.43(6) Å³ for PdTe₂ and 73.35(4) Å³ for PtTe₂), and their short Te...Te contacts are in the range of 3.44–3.56 Å. In addition, IrTe₂, PtTe₂ and PdTe₂ should be similar in electronic structure because the electronegativities of Ir, Pt and Pd are

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nearly the same (i.e., 2.20 for Ir and Pd, and 2.28 for Pt in Pauling scale), although $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) has one more valence electron per formula unit than does IrTe_2 . Thus, one might suggest that the high-pressure behavior of $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) would be similar to that of IrTe_2 . To test this speculation, we performed high-pressure X-ray diffraction experiments for $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) in both angle- and energy-dispersive configurations. $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) was not found to undergo a first-order structural phase transition up to 27 GPa. Only a sudden change in the pressure dependence of the interatomic distances was observed in PdTe_2 at about 19 and 6 GPa at room temperature and at 300 °C, respectively. To understand why IrTe_2 , PdTe_2 and PtTe_2 behave differently under pressure, we compared their electronic structures on the basis of first principles electronic band structure calculations.

2. Synthesis and structure determination under pressure

2.1. Synthesis

A stoichiometric mixture of elemental powders (Pd sponge, 99.9% Aldrich; Pt powder, 325 mesh, 99.9%, Alfa Aesar; Te granules, 30 mesh, 99.99%, Aldrich) was ground and loaded into a quartz tube (~9 cm in length, 10 mm in diameter). The tubes were evacuated to 10^{-2} Torr, sealed and placed into a furnace whose temperature was raised to 850 °C at the rate of 5 °C per hour and kept there for 360 h, following the procedure of Lieth et al. [9] The powder sample was subsequently cooled to room temperature at the rate of 5 °C/h. X-ray powder diffraction data were collected on an INEL CPS 120 diffractometer (Debye–Scherrer geometry). The structure refinements were carried out using the JANA2000 software package [10]. The cell parameters obtained in the present work are in good agreement with those reported in the literature [7] (in italics and within parenthesis), i.e., $a = 4.027(1)$ (*4.026*) Å and $c = 5.223(2)$ (*5.221*) Å for PtTe_2 , and $a = 4.037(2)$ (*4.037*) Å and $c = 5.132(2)$ (*5.126*) Å for PdTe_2 . The corresponding volumes are 73.35(4) (*73.28*) Å³ for PtTe_2 and 72.43(6) (*72.33*) Å³ for PdTe_2 .

2.2. Structure determination

Preliminary high-pressure energy-dispersive X-ray diffraction (EDX) measurements at 20 and 300 °C were carried out at the LURE (France). Experiments reported herein were performed in an angle-dispersive (ADX) mode on the ID30 beamline (ESRF, France) at room temperature (RT) for PtTe_2 , and at RT and at 300 °C for PdTe_2 . The experimental procedure has already been described elsewhere [11]. $M\text{Te}_2$ powder samples were ground to a fine powder in an agate

mortar and loaded in the pressure chamber of a membrane-type diamond anvil cell (DAC). The pressure-transmitting medium added to provide quasi-hydrostatic pressure conditions was N_2 for the experiments at RT, and LiF for those at 300 °C. The ruby fluorescence method [12] was used to measure the in situ pressure.

The diffraction patterns were recorded up to 27 GPa for 2θ angles ranging from 2° to 20° (Figs. 1 and 2). For the 300 °C experiments, the PdTe_2 powder placed in the DAC was resistively heated. The storage ring was operated at 6 GeV and 7–15 mA (single-bunch mode). A channel-cut monochromator was used to select the wavelength of 0.3738 Å. The energy calibration was carried out using the *K*-edge of an iodine foil. The beam was focused via two multilayer mirrors settled in the Kirkpatrick-Baez (KB) configuration, and then collimated with slits, thus defining a spot of 20 μm in

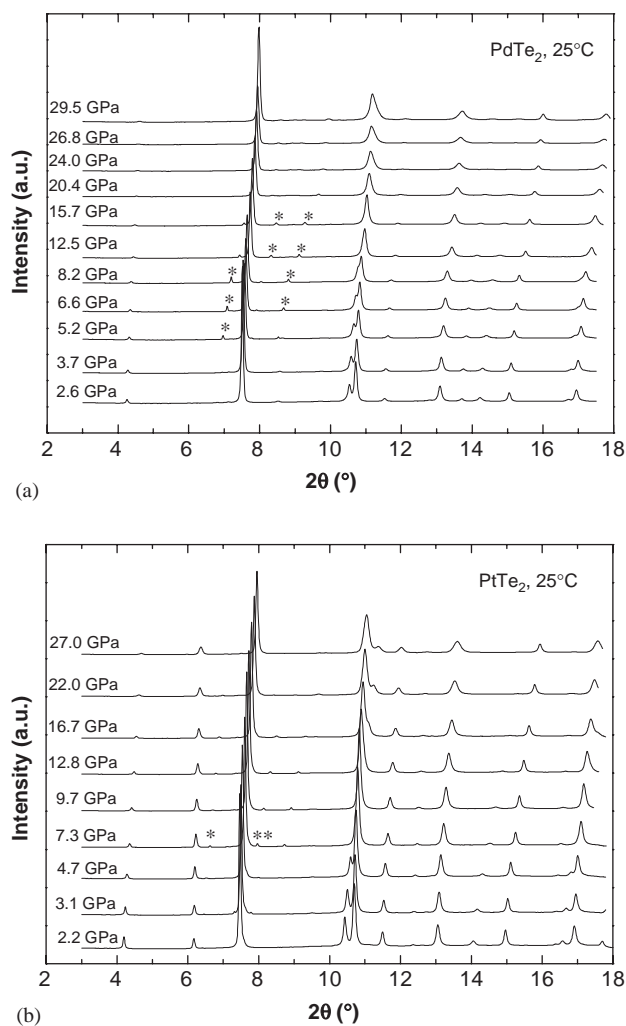


Fig. 1. Angle dispersive diffraction patterns of (a) PdTe_2 and (b) PtTe_2 under pressure during the decompression cycle at room temperature. The asterisks refer to the $\beta\text{-N}_2$ high-pressure phase.

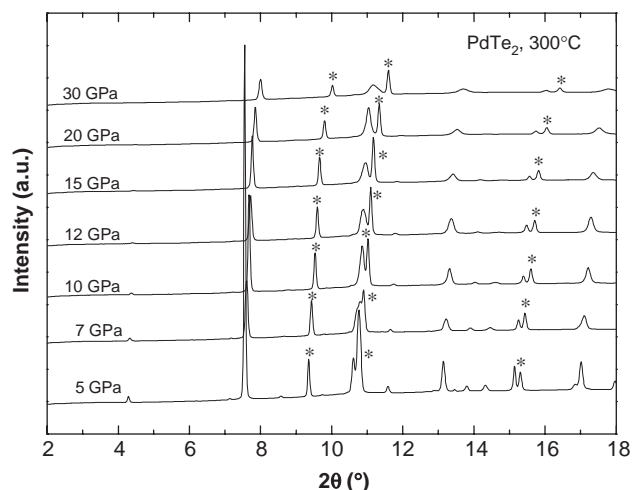


Fig. 2. Angle dispersive diffraction pattern of PdTe₂ up to 30 GPa at 300 °C during the compression cycle. The asterisks refer to the LiF phase.

diameter on the sample. An image plate located at 504.8 mm was employed to collect the pattern (exposure time of 90 s). The image was then converted into an $I(\theta)$ diffraction pattern using the fit2D software [13]. The lattice parameters and atomic positions were refined using the JANA2000 software package [10]. Each recorded diffraction patterns was refined using the Rietveld method with the conventional $P\bar{3}m1$ space group. The peak shape was modeled by a Thompson Cox Hasting function. The peak cutoff was set to $8 \times \text{FWHM}$ and the background was manually adjusted for simplicity because of peak overlapping in the whole range of diffraction pattern.

For each value of the external pressure at RT and 300 °C, it was possible to assign all the diffraction peaks to the CdI₂-type structure. Extra peaks are observed due to the pressure-transmitting medium. At room temperature, these peaks appear above ~ 5 GPa and originate from the formation of the high-pressure phase of nitrogen, $\beta\text{-N}_2$ [14]. At 300 °C, the extra peaks correspond to a crystallized form of the pressure medium LiF. Rietveld refinements data (i.e., the cell parameters, the volumes and the z -coordinates of Te) at RT during the compression cycle are reported in Table 1 for PdTe₂, and Table 2 for PtTe₂. The refinement results of PdTe₂ at 300 °C are given in Table 3. The crystal structures of IrTe₂, PdTe₂ and PtTe₂ at 0.1 MPa and 27 GPa are compared in Table 4.

2.3. Pressure-induced structural change

The pressure dependence of the $M\text{-Te}$, the intralayer Te–Te and the interlayer Te–Te distances at RT is summarized in Fig. 3 for PtTe₂, and in Fig. 4 for PdTe₂. As a function of pressure, the Pt–Te and the Te–Te distances of PtTe₂ exhibit a gradual change, and their

Table 1

Pressure dependence of the cell parameters, the cell volume V and the z coordinate of Te of PdTe₂ at room temperature during the compression cycle

Pressure (GPa)	Cell parameters			z
	a	c	V	
2.6	4.006(1)	5.032(1)	69.93(3)	0.275(2)
3.7	3.995(2)	5.004(2)	69.16(3)	0.277(2)
5.2	3.976(1)	4.963(1)	67.97(2)	0.275(2)
6.6	3.962(1)	4.932(1)	67.05(2)	0.277(2)
8.2	3.947(1)	4.899(1)	66.09(3)	0.280(2)
12.5	3.910(1)	4.822(2)	63.85(3)	0.289(3)
15.7	3.898(4)	4.752(3)	62.52(4)	0.296(3)
20.4	3.851(1)	4.764(1)	61.19(3)	0.343(3)
24.0	3.830(2)	4.748(3)	60.32(5)	0.341(3)
26.8	3.812(3)	4.736(3)	59.61(6)	0.339(3)
29.5	3.794(4)	4.722(4)	58.88(9)	0.337(5)

Table 2

Pressure dependence of the cell parameters, the cell volume V and the z coordinate of Te of PtTe₂ at room temperature during the compression cycle

Pressure (GPa)	Cell parameters			z
	a	c	V	
2.2	4.009(1)	5.100(2)	70.98(2)	0.282(4)
3.1	4.001(1)	5.054(1)	70.06(1)	0.276(3)
4.7	3.990(1)	4.995(2)	68.87(2)	0.280(4)
7.3	3.971(1)	4.907(2)	66.99(2)	0.290(4)
9.7	3.961(1)	4.829(2)	65.62(2)	0.308(4)
12.8	3.940(1)	4.767(2)	64.08(1)	0.286(4)
16.7	3.918(1)	4.687(2)	62.32(2)	0.281(5)
22	3.899(1)	4.597(3)	60.52(3)	0.278(7)
27	3.893(1)	4.536(4)	59.55(7)	0.273(9)

Table 3

Pressure dependence of the cell parameters, the cell volume V and the z coordinate of Te of PdTe₂ at 300 °C during the compression cycle

Pressure (GPa)	Cell parameters			z
	a	c	V	
5	3.993(1)	4.987(3)	68.8(1)	0.283(10)
7	3.976(3)	4.953(9)	67.8(2)	0.364(14)
10	3.937(1)	4.863(1)	65.3(1)	0.351(5)
12	3.914(3)	4.838(5)	64.2(1)	0.353(13)
15	3.927(4)	4.714(11)	63.0(1)	0.346(13)
20	3.894(30)	4.812(17)	63.2(7)	0.339(17)
30	3.835(9)	4.781(7)	60.9(2)	0.333(9)

distances keep the same trend (Fig. 3), i.e., intralayer Te–Te > interlayer Te–Te > Pt–Te. However, the corresponding distances of PdTe₂ undergo an abrupt change at ~ 19 GPa (Fig. 4). Namely, below ~ 19 GPa,

Table 4

Crystal structures of the polymeric CdI₂-type structures of PdTe₂, PtTe₂ and IrTe₂ at 0.1 MPa and 27 GPa at ambient temperature

	IrTe ₂		PdTe ₂		PtTe ₂	
	0.1 MPa ^a	27 GPa ^b	0.1 MPa ^c	27 GPa ^d	0.1 MPa ^c	27 GPa ^d
<i>a</i> (Å)	3.9284(2)	3.771	4.037(3)	3.812(3)	4.026(5)	3.893(1)
<i>c</i> (Å)	5.4040(1)	4.829	5.126(4)	4.736(3)	5.221(5)	4.536(4)
<i>V</i> (Å ³)	72.22(1)	59.12	72.33(9)	59.61(6)	73.28(9)	59.55(7)
<i>c/a</i>	1.38	1.28	1.27	1.24	1.3	1.17
<i>Z</i>	0.2536(1)	0.283	0.247(5)	0.339(3)	0.254(5)	0.273(9)

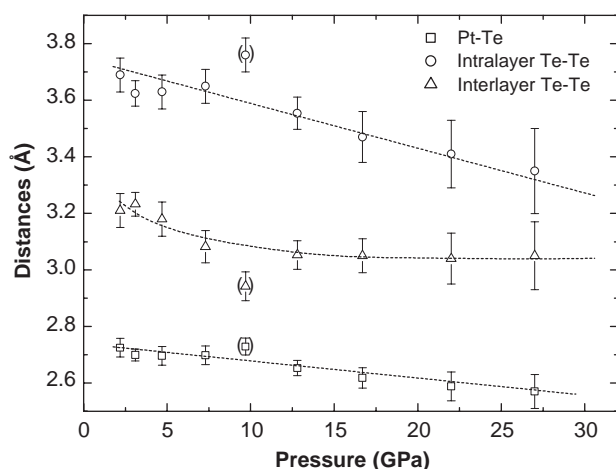
^aRefs. [2,3c].^bThe cell parameters were taken from experiment, and the *z* value of Te from geometry optimization.^cRef. [9].^dThis work.

Fig. 3. Pressure dependence of the Pt–Te, the intralayer Te–Te and the interlayer Te–Te distances of PtTe₂ at room temperature. The brackets indicate that the data points collected at 9.2 GPa do not follow the smooth variation of the interatomic distances vs. pressure curve.

the distances show the ordering, intralayer Te–Te > interlayer Te–Te > Pd–Te, as in the case of PtTe₂. Above ~19 GPa, they show the ordering, intralayer Te–Te > Pd–Te > interlayer Te–Te, so that the structure of PdTe₂ above ~19 GPa can be described as made up of $\frac{2}{\infty}$ [Te] double sheets encapsulating Pd atoms. The Te network of PdTe₂ above ~19 GPa exhibit similar structural features to the As-type high-pressure form of elemental Te [15] (Fig. 5). The short Te–Te distances of ~2.68 Å are even shorter than those found in elemental tellurium or in [Te_n]²⁻ anions (i.e. ~2.75 Å) [16].

To gain some insight into the abrupt structural change of PdTe₂ at RT, additional experiments were performed at 300 °C up to 27 GPa (Fig. 2). The results of the refinements and the pressure dependence of the Pd–Te and Te–Te distances at 300 °C are summarized in Table 3 and Fig. 6. The pressure dependence of the Pd–Te and Te–Te distances at 300 °C is similar to that observed at RT. Only the pressure at which the abrupt

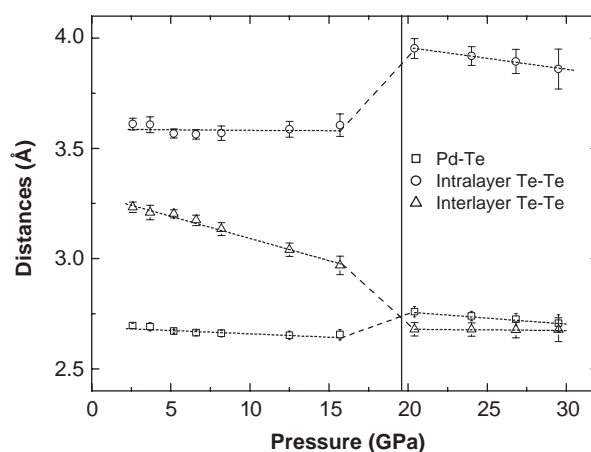


Fig. 4. Pressure dependence of the Pd–Te, the intralayer Te–Te and the interlayer Te–Te distances of PdTe₂ at room temperature. The vertical line represents a hypothetical frontier between the CdI₂-type structure (below ~19 GPa) and the modified CdI₂-type structure (above ~19 GPa).

distance change occurs is modified. The higher the temperature, the lower the pressure necessary for the structural reorganization (i.e., ~6 GPa at 300 °C vs. ~19 GPa at RT).

The abrupt structural change in PdTe₂ cannot be a first-order phase transition because the cell volume decreases smoothly with pressure as shown in Fig. 7. It is expected that the structure rearrangement is associated with a second-order phase transition, although this cannot be ascertained from our preliminary calculations based on the thermodynamic potentials derived from the first derivative of the volume. In summary, unlike the case of IrTe₂, both PtTe₂ and PdTe₂ do not undergo a first-order structural phase transition under the pressure and temperature ranges employed in our experiments. However, in contrast to the case of PtTe₂, PdTe₂ seems to display a second-order phase transition beyond a certain pressure, which decreases upon increasing the temperature. To account

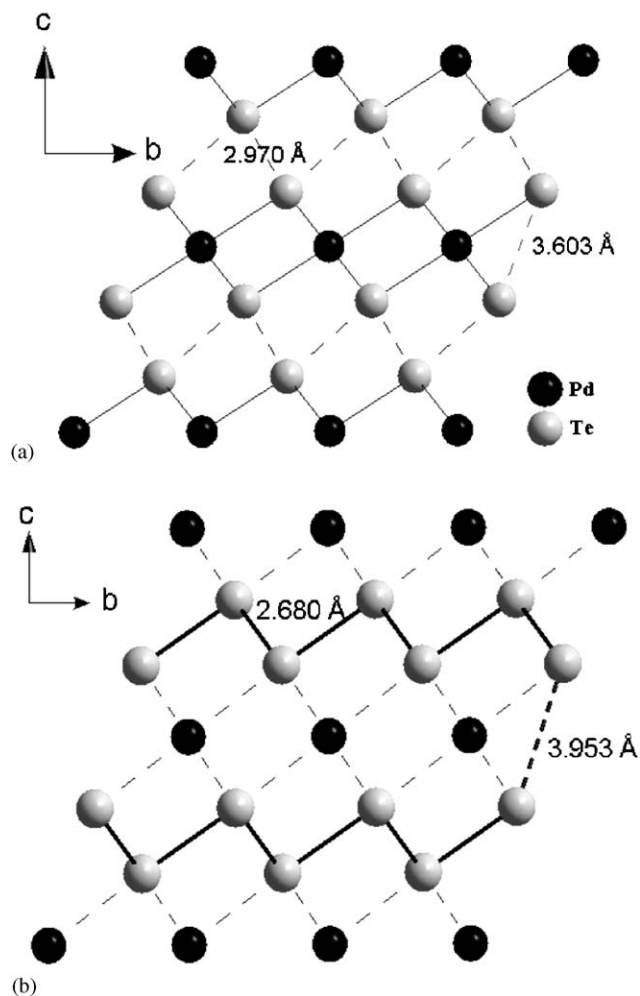


Fig. 5. Projection views of PdTe₂ at (a) 15 GPa and (b) 20 GPa.

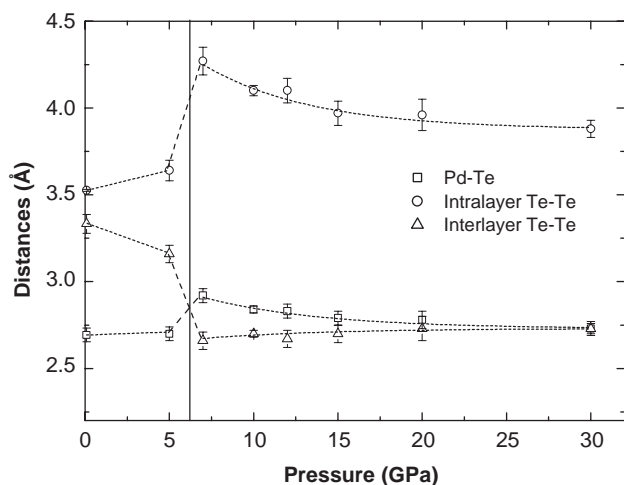


Fig. 6. Pressure dependence of the Pd–Te, the intralayer Te–Te and the interlayer Te–Te distances of PdTe₂ at 300 °C.

for this difference between $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) and IrTe_2 , we compare their electronic structures in the next section.

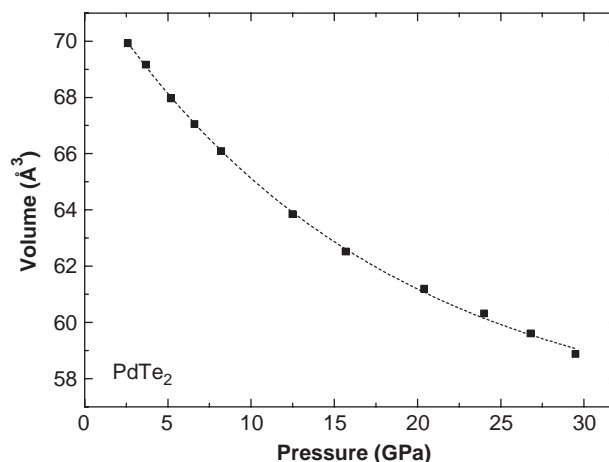


Fig. 7. Pressure dependence of the cell volume of PdTe₂. $B_0 = 101.5$ GPa and $V_0 = 71.29$ Å³ are obtained from the Birch–Murnaghan second-order equation of state fit.

It is of interest to consider why such an abrupt structural change as observed for PdTe₂ does not occur in PtTe₂. We note from Fig. 4 that, when the pressure increased beyond ~ 19 GPa, the interlayer Te–Te distance collapses to form the $\frac{2}{\infty}$ [Te] double sheets while increasing the Pd–Te bond length (from ~ 2.70 Å to ~ 2.80 Å). In other words, the strengthening of the Te–Te bonding takes place at the expense of weakening the Pd–Te bonding. The Pt $5d$ orbitals are more extended than the Pd $4d$ orbitals, so that the Pt–Te bond is more strongly covalent bonded than the Pd–Te bond. Therefore, it would be energetically unfavorable to decrease the interlayer Te–Te bonding at the expense of increasing the Pt–Te bonding.

3. Electronic structures of IrTe₂, PdTe₂ and PtTe₂

3.1. Computational details

First principles linearized full potential plane wave (FP-LAPW) calculations with non-spin-polarization were carried out for the CdI₂ structures of IrTe₂, PtTe₂ and PdTe₂ using the WIEN2k program package [17] within the generalized gradient approximation [18] for the exchange–correlation energy. The cell parameters and the atomic positions used for calculation were the experimental values taken from the literature (at 0.1 MPa), from our Rietveld refinements (at 27 GPa) for PtTe₂ and PdTe₂, and from our geometry optimization with the cell parameters taken from the high-pressure experiments for IrTe₂. For the 0.1 MPa structure, we employed the muffin-tin radii of 2.5 au for the metal and 2.4 au for Te. For the 27 GPa structure, we employed the muffin-tin radii of 2.4 au for both elements. The basis set cutoff parameters were

$G_{\max} = 14 \text{ Bohr}^{-1}$ and $R_{\text{mt}}K_{\max} = 8$. Integrations over the irreducible wedge of the Brillouin zone were performed using a 200k-point regular mesh (24k-points in the irreducible zone).

3.2. Density of states and oxidation states

The plots of the electronic DOS calculated for IrTe₂, PtTe₂ and PdTe₂ are compared in Fig. 8. The solid lines refer to the total DOS curves, the dotted lines and thick lines to the partial DOS for the *d* orbitals of the transition metal atoms and for the *p* orbitals of Te, respectively, and the vertical lines to the Fermi level. In capturing the essential features of the DOS curves, one often considers the oxidation state of the metal atoms. With the charge balance (Ir³⁺)(Te^{1.5-})₂ for h-IrTe₂, the oxidation state Ir³⁺ (*d*⁶) given by the ionic electronic counting scheme predicts that the *t*_{2g} bands are completely filled and the *e*_g-block bands are empty. These predictions are only in approximate agreement with the total and partial DOS plots shown in Fig. 8a. The *e*_g-block bands of h-IrTe₂ may be assigned to the energy region between 1.4 and 3.6 eV. With the ionic picture [19–21] for a transition metal *d*⁶ ion in an octahedral site, in which the main group ligand atoms are assumed to have the inert gas electron configuration (e.g., Te²⁻), the *t*_{2g}-block bands are completely filled and the *e*_g-block bands are completely empty. Furthermore, in this picture, the metal orbitals should be the dominant

character of the *t*_{2g}- and *e*_g-block bands. However, in the *e*_g-block bands of Fig. 8a, the Ir *d*-orbital contribution is smaller than the Te orbital contribution by a factor of two or greater. Thus, the “missing” Ir *d*-orbital contribution in the *e*_g-block bands occurs in the bands lying below them. Consequently, the actual amount of the occupied *d* electron density is greater than six.

In a similar manner, one may assign the *e*_g-bands of PdTe₂ and PtTe₂ to the energy region between -0.2 and 2.2 eV. If the oxidation state of +4 is assumed for the metal *M* of *M*Te₂ (*M* = Pt, Pd), the *d* electron count for *M* would be *d*⁶ so that the *e*_g-block bands should be empty. However, the partial DOS plots of Figs. 8b and c reveal that the *e*_g-block bands are dominated by the Te *p*-orbital contributions. Therefore, the amount of occupied *d* electron density in *M*Te₂ (*M* = Pt, Pd) could be close to 10 as if the metal was in the oxidation state close to 0. As has been pointed out already [19–21], the concept of the ionic electron counting scheme becomes inadequate and leads to an erroneous picture for the electronic structures for compounds of late transition metal atoms with weak to medium electronegative main group elements such as Te.

4. Discussion and concluding remarks

It is noted that the shortest interlayer Te...Te distances of *M*Te₂ under ambient conditions (3.46 Å

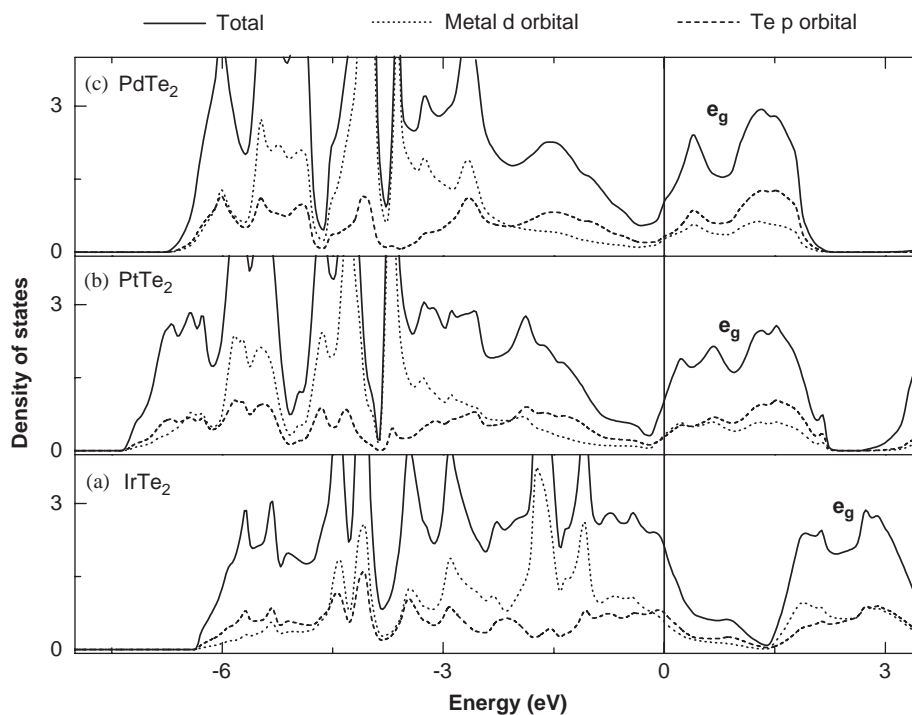


Fig. 8. Plots of the total DOS (solid line), the partial DOS for the metal *d* orbitals (dotted line) and the DOS for the Te *p* orbitals (dashed line): (a) IrTe₂, (b) PtTe₂ and (c) PdTe₂.

for $M = \text{Pt}$ and 3.33 \AA for $M = \text{Pd}$) are comparable to the shortest interchain Te...Te distance (3.47 \AA) in trigonal tellurium [22] and the shortest interlayer Te...Te distance (3.47 \AA) in monoclinic tellurium [23]. Furthermore, the hexagonal net of the As-type tellurium [15a] is quite similar in structure to that of $M\text{Te}_2$, and so are their interlayer Te...Te distances (3.48 \AA). These observations suggest that the charge distribution on tellurium in $M\text{Te}_2$ is quite similar to that in elemental tellurium. Therefore, it is appealing to conclude that the tellurium of $M\text{Te}_2$ has the oxidation state close to 0 rather than to -2 , and hence the metal M of $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) has the oxidation state close to 0. This conclusion is consistent with the observation that M and Te have a similar electronegativity (2.1 for Te and ~ 2.2 for M). To a first approximation, therefore, the M -Te bonds of $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) are primarily covalent in character. Consequently, it is difficult to describe the electronic structure of $M\text{Te}_2$ in terms of the ionic electron counting scheme.

The pressure induced structural transitions of IrTe_2 is explained by noting that an external pressure applied shortens mainly the Te...Te distances to raise the energy of the Te p -block bands, and this induces electron transfer from the Te p -block bands to the Ir d -block bands, because the d -block levels are not completely filled. As discussed in the previous section, the d -block energy levels of $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$) are practically completely filled. Consequently, the electron transfer Te $p \rightarrow M d$ cannot take place even if the Te p -block bands are raised in energy by shortening the Te...Te distances. This explains why such pressure-induced structural phase transitions as observed in h- IrTe_2 do not take place in $M\text{Te}_2$ ($M = \text{Pt}, \text{Pd}$).

Nevertheless, $M\text{Te}_2$ ($M = \text{Pd}, \text{Pt}$) exhibits a slightly different response to pressure. When the pressure increased beyond $\sim 19 \text{ GPa}$, the interlayer Te-Te distance of PdTe_2 collapses to form the $\frac{2}{\infty} [\text{Te}]$ double sheets while increasing the Pd-Te bond length. A similar structural change does not occur in PtTe_2 , probably because the Pt-Te bond is more strongly covalent bonded than the Pd-Te bond.

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